

ALL DIMENSIONS IN MM.

CATALOG OUTLINE
TYPE R82



Powerex General Purpose Rectifier Diodes are designed with high blocking voltage capability and low forward voltage drop to minimize conduction losses. These are packaged in hermetic, ceramic Pow-R-Disc packages which can be mounted using commercially available clamps and heatsinks or fully assembled to a variety of air or water cooled heat exchangers.

FEATURES:

- Low On-State Voltage
- Hermetic Ceramic Package
- Excellent Surge and I²t Ratings

APPLICATIONS:

- DC Power Supplies
- Input Rectifiers

ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.
EXAMPLE: R8205207XXOO is a 5200V-690A General Purpose Diode with a typical reverse recovery time of 30µs.

PART	Voltage Rating V _{DRM} -V _{RRM}	Voltage Code	Current Rating I _{tavg}	Current Code	Reverse Recovery t _{RR}	Lead Code
R820	5200V	52	690A	07	XX	OO
	5000V	50				
	4800V	48			30µs typical	
	4400V	44				

Revised: 2/22/2008

Absolute Maximum Ratings

Characteristic	Symbol	Rating	Units
Repetitive Peak Reverse Voltage	V_{RRM}	5200	Volts
Non-repetitive Transient Peak Reverse Voltage	V_{RSM}	$V_{RRM} + 100$	Volts
Average On-State Current, $T_C = 100^\circ\text{C}$	$I_{F(Avg.)}$	690	A
RMS On - State Current, $T_C = 100^\circ\text{C}$	$I_{F(RMS)}$	1084	A
Average On-State Current, $T_C = 55^\circ\text{C}$	$I_{F(Avg.)}$	1035	A
RMS On - State Current, $T_C = 55^\circ\text{C}$	$I_{F(RMS)}$	1626	A
Peak One Cycle Surge Current, 60Hz, $V_R = V_{RRM}$	I_{FSM}	7,500	A
Fuse Coordination I^2t , 60Hz	I^2t	2.34E+05	A^2s
Peak One Cycle Surge Current, 50Hz, $V_R = 0V$	I_{FSM}	6,938	A
Fuse Coordination I^2t , 50Hz	I^2t	2.41E+05	A^2s
Operating Temperature	T_j	-40 to+150	$^\circ\text{C}$
Storage Temperature	$T_{Stg.}$	-50 to+190	$^\circ\text{C}$
Approximate Weight		0.5	lb
		0.23	Kg
Mounting Force		3,000 - 3,500	lbs
		13.3 - 15.5	Knewtons

Information presented is based upon manufacturers testing and projected capabilities. This information is subject to change without notice. The manufacturer makes no claim as to suitability for use, reliability, capability or future availability of this product.

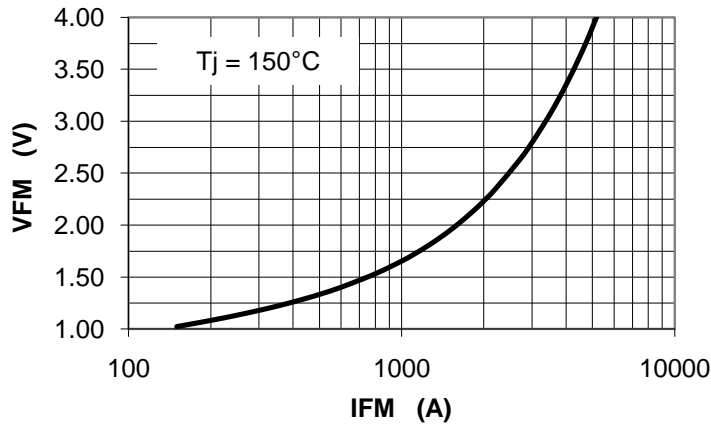
Electrical Characteristics, T_j=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Repetitive Peak Reverse Leakage Current	I _{RRM}	T _j =150°C, V _{RRM} =Rated		50	75	ma
Peak On-State Voltage	V _{FM}	T _j =25°C, I _{FM} = 1500 A			1.65	V
V _{FM} Model, Low Level	V ₀	T _j =150°C			1.00	V
V _{FM} = V ₀ + r•I _{FM}	r	15% I _{FM} - π•I _{FM}			6.20E-04	Ω
V _{FM} Model, High Level	V ₀	T _j =150°C			1.12	V
V _{FM} = V ₀ + r•I _{FM}	r	π•I _{FM} - I _{FSM}			5.57E-04	Ω
V _{FM} Model, 4-Term	A	T _j =150°C			0.209	
V _{FM} = A + B•Ln(I _{FM}) +	B	15%I _{FM} - I _{FSM}			1.69E-01	
C•(I _{FM}) + D•(I _{FM}) ^{1/2}	C				5.93E-04	
	D				-1.00E-02	
Reverse Recovery Time	t _{RR}	T _j =25°C, I _{FM} =400A di _R /dt = 25 A/μs		30		μs

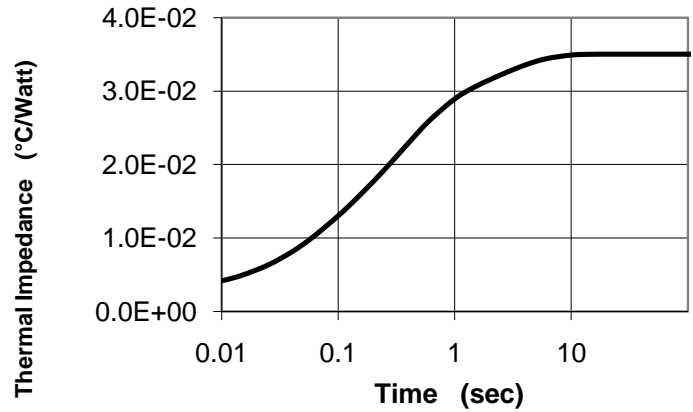
Thermal Characteristics

Characteristic	Symbol	Test Conditions	min	Rating		Units	
				typ	max		
Thermal Resistance							
Junction to Case	Rθ _{jc}	Double side cooled		0.03	0.035	°C/Watt	
Case to Sink	Rθ _{cs}	Double side cooled		0.012	0.015	°C/Watt	
Thermal Impedance Model	Zθ _{jc}	Double side cooled					
$Z_{\theta_{jc}}(t) = \sum(A(N) \cdot (1 - \exp(-t/\tau(N))))$		where:	N =	1	2	3	4
			A(N) =	2.536E-03	6.394E-03	1.818E-02	7.915E-03
			Tau(N) =	7.988E-04	5.286E-02	3.296E-01	2.391E+00

Maximum On-State Voltage Drop

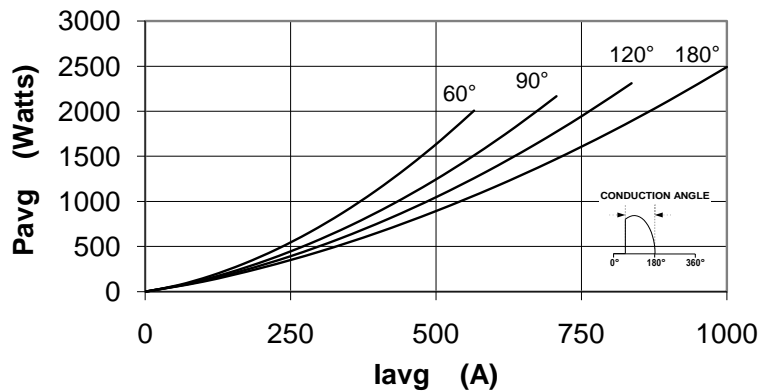


MAXIMUM TRANSIENT THERMAL IMPEDANCE



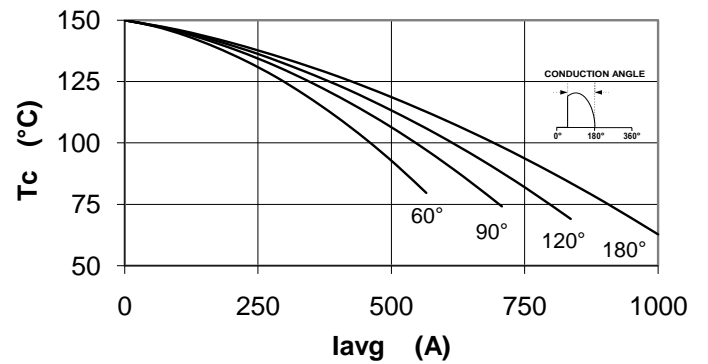
Maximum On-State Power Dissipation

Sinusoidal Waveform



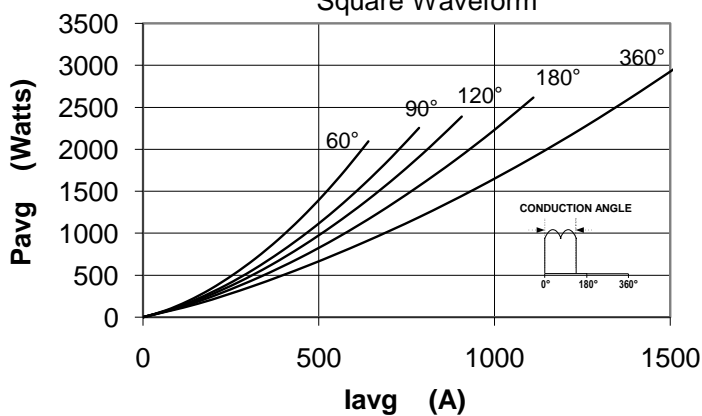
Maximum Allowable Case Temperature

Sinusoidal



Maximum On-State Power Dissipation

Square Waveform



Maximum Allowable Case Temperature

Square Waveform

